

# PHOTON IS OUR BUSINESS

#### Si APD

#### S15415 series

### High-speed, compact Si APD that does not require temperature adjustment

The S15415 series is a gain-stabilized APD (GS APD) with a built-in temperature compensation function inside the sensor. This realizes constant gain without the need for temperature adjustment. It is suitable for laser monitors of optical rangefinders used in a wide range of applications, from consumer to industrial.

#### Features

- Built-in temperature compensation function
- **→** Compact package: 2.0 × 1.8 × 0.85<sup>t</sup> mm
- Peak sensitivity wavelength: 840 nm (M=50)
- → High-speed response: Cutoff frequency=500 MHz typ.
  (λ=905 nm, M=50)

#### Applications

Optical rangefinders

#### Structure

Parameter	S15415-02	S15415-05	Unit
Photosensitive area*1	ф0.2	φ0.5	mm
Package	Glass epoxy		
Sealing material	Silicone resin		

<sup>\*1:</sup> Area in which a typical gain can be obtained

#### **■** Absolute maximum ratings

Parameter	Symbol	Specification	
Anode reverse current (DC)	IR anode max	0.1	mA
Forward current	IF max	10	mA
Operating temperature*2	Topr	-30 to +105	°C
Storage temperature*2	Tstg	-40 to +105	°C
Soldering temperature	Tsol	260 (3 times)*3	°C

<sup>\*2:</sup> No dew condensation

When there is a temperature difference between a product and the surrounding area in high humidity environments, dew condensation may occur on the product surface. Dew condensation on the product may cause deterioration in characteristics and reliability.

Note: Exceeding the absolute maximum ratings even momentarily may cause a drop in product quality. Always be sure to use the product within the absolute maximum ratings.

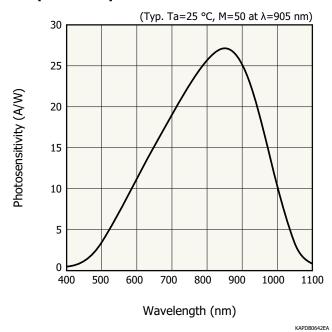
<sup>\*3:</sup> Reflow soldering, JEDEC J-STD-020 MSL 2a, see P.5

#### **■** Electrical and optical characteristics (Ta=25 °C, unless otherwise noted)

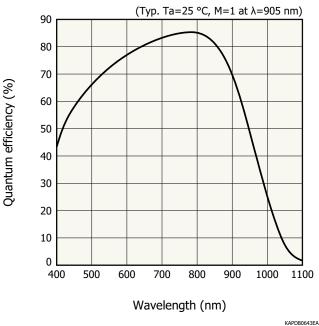
Dayamatar	Symbol Condition		S15415-02			S15415-05			Linit
Parameter	Symbol	Condition	Min.	Тур.	Max.	Min.	Тур.	Max.	Unit
Spectral response range	λ				400 to	1100			nm
Peak sensitivity wavelength	λр		-	840	-	-	840	-	nm
Photosensitivity	S	λ=905 nm, M=1	-	0.5	-	-	0.5	-	A/W
Quantum efficiency	QE	λ=905 nm, M=1	-	70	-	-	70	-	%
Operating reverse voltage	Vop	Gain-stabilized mode operation*4	185 + 1.1 × (Ta opr - 25)*5	-	-	185 + 1.1 × (Ta opr - 25)*5	-	-	V
Temperature coefficient of operating reverse voltage	ΔΤVορ		-	1.1	-	-	1.1	-	V/°C
Dark current	ID	Gain-stabilized mode operation*4	-	20	200	-	40	400	pА
Dark current temperature coefficient	ΔTid	M=50	-	1.1	-	-	1.1	-	times/°C
Cutoff frequency	fc	M=50, RL=50 Ω λ=905 nm, -3 dB	-	500	-	-	500	-	MHz
Terminal capacitance	Ct	M=50, f=1 MHz	-	0.5	-	-	1.1	-	pF
Excess noise figure	Х	M=50, λ=905 nm	-	0.3	-	-	0.3	-	-
Gain	М	Gain-stabilized mode operation*4, λ=905 nm	40	50	60	40	50	60	-
Gain control range	-	λ=905 nm	-	30 to 100	-	-	30 to 100	-	-

<sup>\*4:</sup> Apply bias voltage to anode. IR anode limit=10 µA, guard pin=GND

#### Spectral response



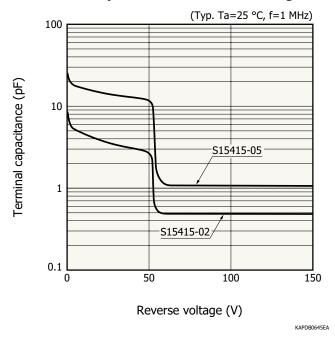
#### - Quantum efficiency vs. wavelength



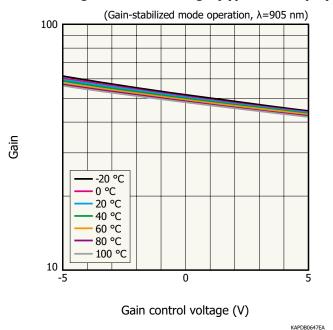
KAPDB0643EA

<sup>\*5:</sup> Ta opr=assumed maximum operating temperature (°C)

#### Terminal capacitance vs. reverse voltage

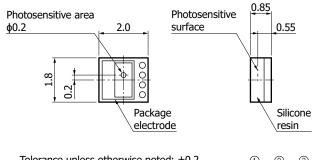


#### **Gain vs. gain control voltage (typical example)**

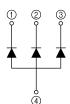


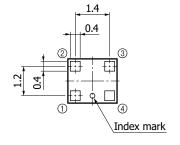
#### Dimensional outlines (unit: mm)

#### S15415-02



Tolerance unless otherwise noted:  $\pm 0.2$ Chip position accuracy with respect to package electrode pattern center: X, Y  $\leq \pm 0.2$ 

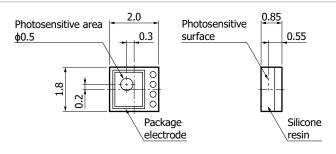


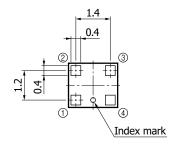


1	Gain control	Gain control voltage input (connect to GND)
2	Output	APD output
3	Guard	Leakage current output (connect to GND)
4	Anode	Bias voltage input

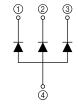
KAPDA0229E

#### S15415-05





Tolerance unless otherwise noted:  $\pm 0.2$  Chip position accuracy with respect to package electrode pattern center: X, Y  $\leq \pm 0.2$ 



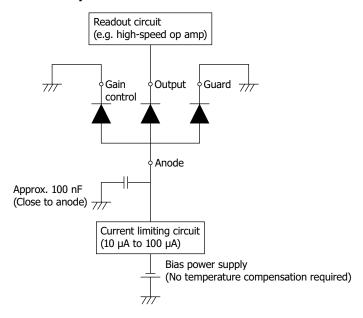
1	Gain control	Gain control voltage input (connect to GND)
2	Output	APD output
3	Guard	Leakage current output (connect to GND)
4	Anode	Bias voltage input

KAPDA0230EA

#### Recommended land pattern

## 0.4 O.4 NAPPC0138EA

#### - Connection example



- $\cdot$  The gain can be controlled by applying a voltage to the gain pin.
- · We recommend connecting a capacitor near the anode pin to stabilize the bias voltage.

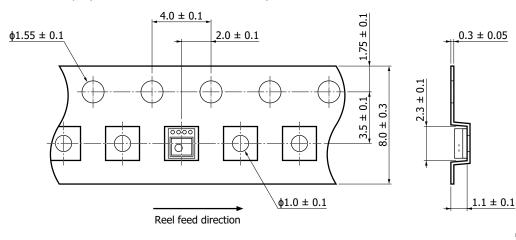
KAPDC0137EA

#### Standard packing specifications

■ Reel (conforms to JEITA ET-7200)

Appearance	Hub diameter	Tape width	Material	Electrostatic characteristics
φ180 mm	ф60 mm	8 mm	PS	Conductive

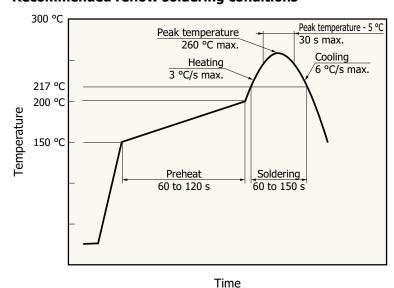
■ Embossed tape (unit: mm, material: PS, conductive)



- Packing quantity 1000 pcs/reel
- Packing state

  Reel and desiccant in moisture-proof packaging (vacuum-sealed)

#### Recommended reflow soldering conditions



· After unpacking, store it in an environment at a temperature of 30 °C or less and a humidity of 60% or less, and perform soldering within 4 weeks.

KAPDC0139EA

 The effect that the product receives during reflow soldering varies depending on the circuit board and reflow oven that are used. When you set reflow soldering conditions, check that problems do not occur in the product by testing out the conditions in advance.

KMPDB0405EC

#### S15415 series

#### Baking

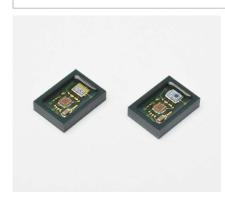
If three months have passed without unpacking or the above storage period has passed after unpacking, perform baking before reflow soldering to dehumidify. For the baking, refer to the precautions "Surface mount type products."

- Recommended baking conditions
- · Temperature: 150 °C, 3 hours, up to twice

Note: When you set baking conditions, check that problems do not occur in the product by testing out the conditions in advance.

#### Related products

#### Photosensor with front-end IC S16429 series



This device is for direct TOF (time-of-flight) distance measurement, integrating the S15415 series and a transimpedance amplifier. It offers low-noise and high-speed response.

#### Features

- Stable gain against temperature fluctuations
- No gain adjustment according to individual differences required
- → High-speed response
- **Low noise**

Type no.	Built-in element	Cutoff frequency	
S16429-01CT	S15415-02	300 MHz	
S16429-02CT	S15415-05	280 MHz	

#### Related information

www.hamamatsu.com/sp/ssd/doc\_en.html

- Precautions
- Disclaimer
- · Surface mount type products
- Technical note
- · Si APD

The content of this document is current as of February 2024.

Product specifications are subject to change without prior notice due to improvements or other reasons. This document has been carefully prepared and the information contained is believed to be accurate. In rare cases, however, there may be inaccuracies such as text errors. Before using these products, always contact us for the delivery specification sheet to check the latest specifications.

The product warranty is valid for one year after delivery and is limited to product repair or replacement for defects discovered and reported to us within that one year period. However, even if within the warranty period we accept absolutely no liability for any loss caused by natural disasters or improper product use. Copying or reprinting the contents described in this material in whole or in part is prohibited without our prior permission.

#### AMAMATSU

www.hamamatsu.com

HAMAMATSU PHOTONICS K.K., Solid State Division

1126-1 Ichino-cho, Chuo-ku, Hamamatsu City, 435-8558 Japan, Telephone: (81)53-434-3311, Fax: (81)53-434-5184

LOSA: HAMAMATSU CORPORATION: 360 Footbill Road, Bridgewater, NJ 08807, U.S.A.; Telephone: (1)908-231-0960, Fax: (1)908-231-1218

Germany: HAMAMATSU CORPORATION: 360 Footbill Road, Bridgewater, NJ 08807, U.S.A.; Telephone: (1)908-231-0960, Fax: (1)908-231-1218

Germany: HAMAMATSU PHOTONICS DEUTSCHLAND GMBH: Arzbergerstr. 10, 82211 Herrsching am Ammersee, Germany, Telephone: (49)8152-375-0, Fax: (49)8152-265-8 E-mail: info@hamamatsu.de

France: HAMAMATSU PHOTONICS FRANCE S.A.R.L.: 19 Rue du Saule Trapu, Parc du Moulin de Massy, 91882 Massy Cedex, France, Telephone: (33)1 69 53 71 00, Fax: (33)1 69 53 71 00, Fax: (34)1 10 E-mail: info@hamamatsu.fr

United Kingdom: HAMAMATSU PHOTONICS UK LIMITED: 2 Howard Count,10 Tewin Road, Welwyn Garden City, Hertfordshire, AJ7 18W, UK, Telephone: (44)1707-325777 E-mail: info@hamamatsu.co.uk

North Europe: HAMAMATSU PHOTONICS ONDEDN AB: Torshamnsgatan 35, 16440 Kista, Sweden, Telephone: (46)8-509-031-01, Fax: (46)8-509-031-01 E-mail: info@hamamatsu.se

Italy: HAMAMATSU PHOTONICS (TAILA S.R.L.: Strada della Moia, 1 int. 6 20044 Arese (Milano), Italy, Telephone: (49)02-93 58 17 33, Fax: (39)02-93 58 17 41 E-mail: info@hamamatsu.it

China: HAMAMATSU PHOTONICS (CHINN) CO., LTD.: 1201, Tower B, Jiaming Center, 27 Dongsanhuan Bellu, Chaoyang District, 100020 Beijing, PR. China, Telephone: (86)10-6586-6006, Fax: (86)10-6586-6006, Fax: (86)10-6586-6008, F